



GaAs MMIC I/Q UPCONVERTER 17.6 - 23.7 GHz

Typical Applications

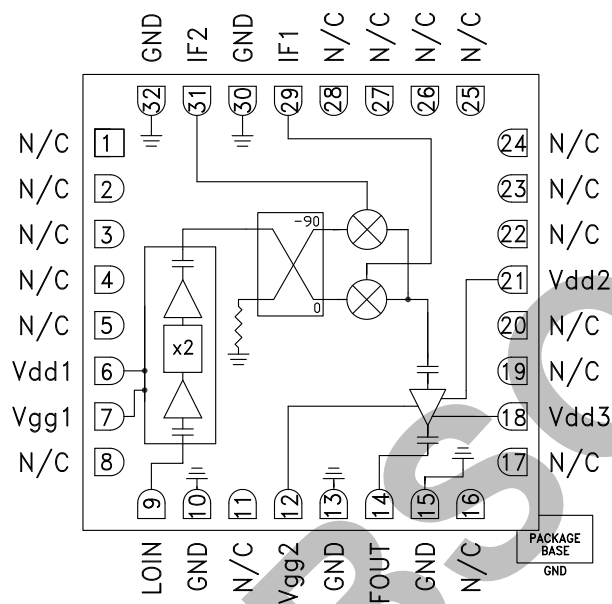
The HMC819LC5 is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

Features

- High Conversion Gain: 15 dB
- Excellent Sideband Rejection: -35 dBc
- 2 LO to RF Isolation: 12 dB
- High Output IP3: +35 dBm
- 32 Lead 5x5 mm SMT Ceramic Package: 25 mm²

Functional Diagram



General Description

The HMC819LC5 is a compact GaAs MMIC I/Q upconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 15 dB with -35 dBc of sideband rejection. The HMC819LC5 utilizes a driver amplifier preceded by an I/Q mixer where the LO is driven by an active x2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC819LC5 is a much smaller alternative to hybrid style single sideband upconverter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

Electrical Specifications ^{[1][2]}, $T_A = +25^\circ\text{C}$

IF = 3300 MHz, LO = +7 dBm, Vgg1 = -1.7V Vdd1, 2, 3 = +5V, Idd2 + Idd3 = 270 mA USB ^{[1][3]}

Parameter	Min.	Typ.	Max.	Units
Frequency Range, RF		17.6 - 23.7		GHz
Frequency Range, LO		6.6 - 11.6		GHz
Frequency Range, IF		DC - 3.75		GHz
Conversion Gain	11	15	17	dB
Sideband Rejection		-35		dBc
1 dB Compression (Output)	19	23		dBm
2 LO to RF Isolation		12		dB
2 LO to IF Isolation ^[2]		20		dB
IP3 (Output)		35		dBm
Supply Current Idd1		95	120	mA
Supply Current Idd2 + Idd3 ^[3]		270	300	mA

[1] Unless otherwise noted all measurements performed with low side LO, IF = 3300 MHz and external IF 90° hybrid.

[2] Data taken without external IF 90° hybrid.

[3] Adjust Vgg2 between -2 to 0V to achieve Idd2 + Idd3 = 270 mA Typical.

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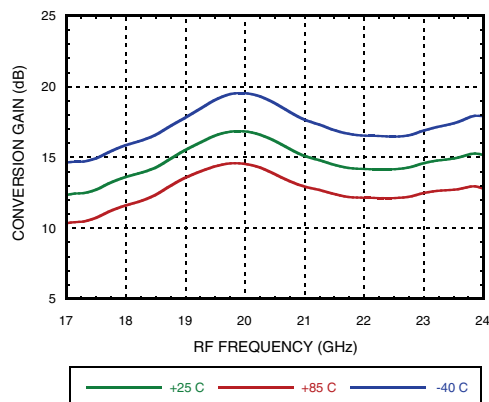
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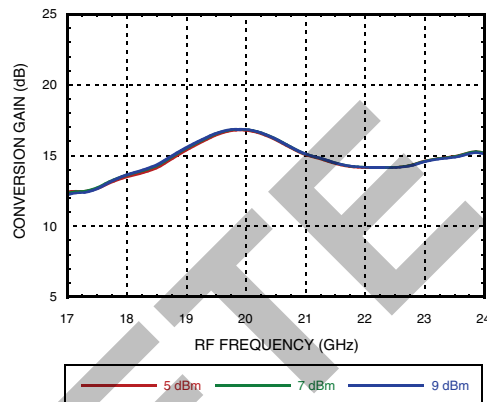
GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2500 MHz

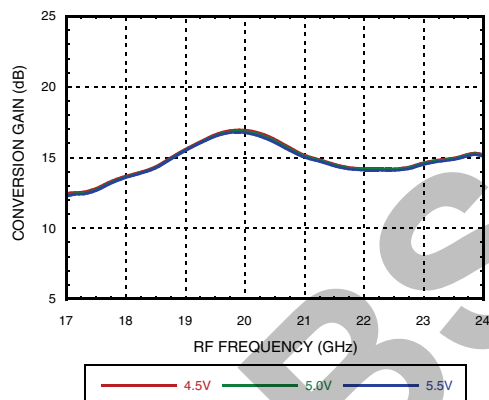
Conversion Gain, USB vs. Temperature



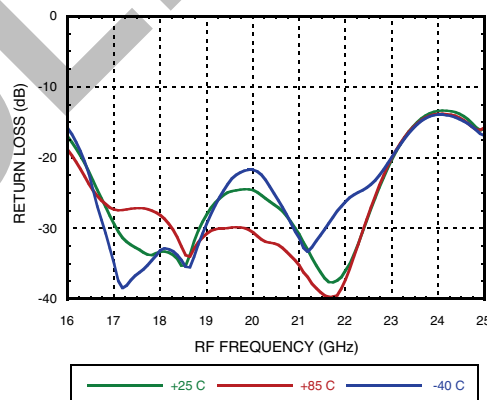
Conversion Gain, USB vs. LO Drive



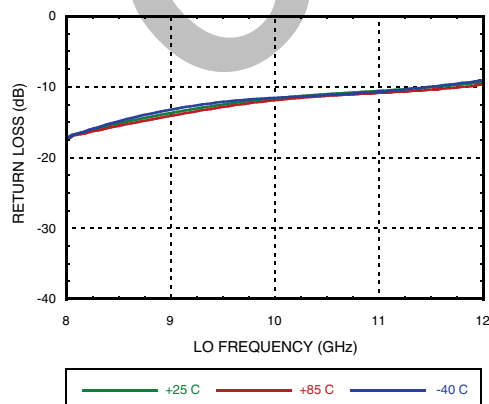
Conversion Gain, USB vs. Vdd



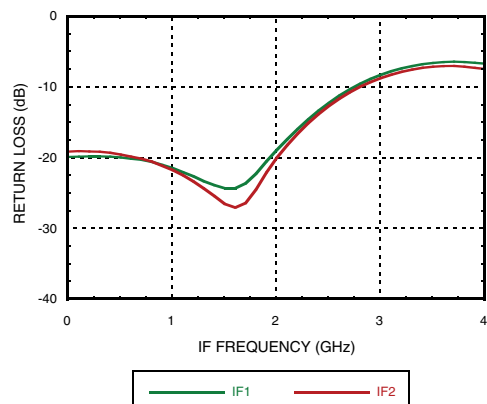
RF Return Loss vs. Temperature



LO Return Loss vs. Temperature



IF Return Loss ^[1]



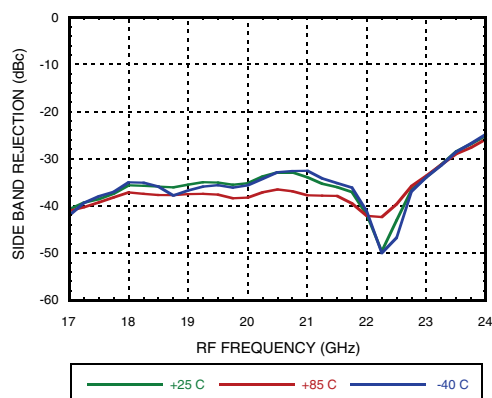
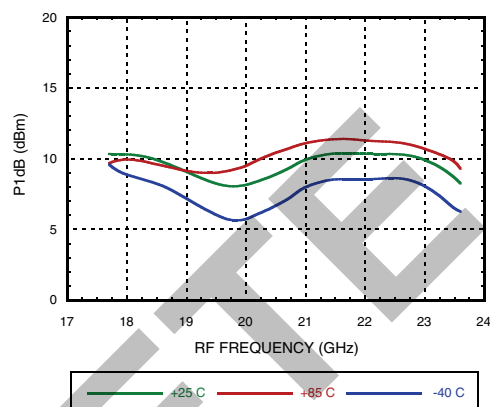
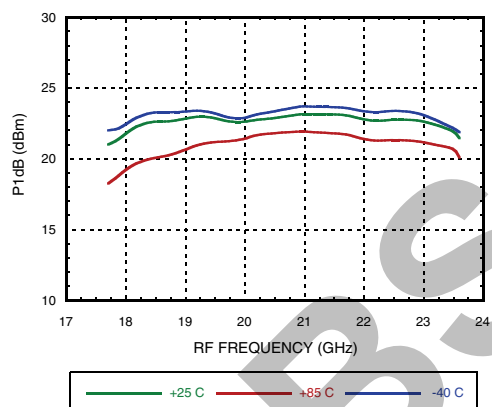
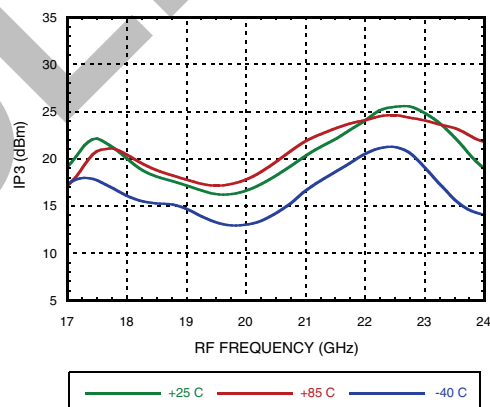
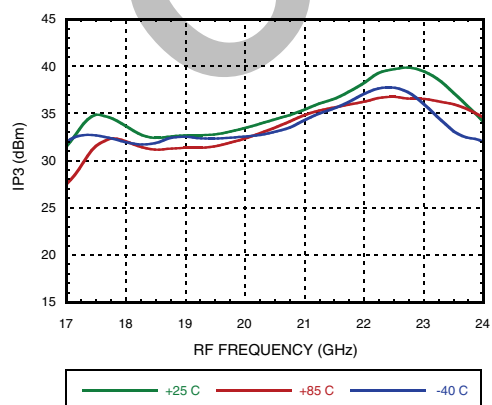
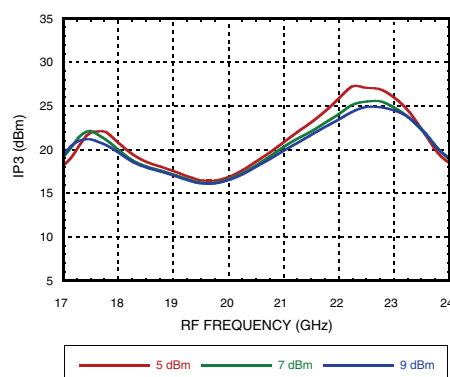
[1] Data taken without external IF 90° hybrid

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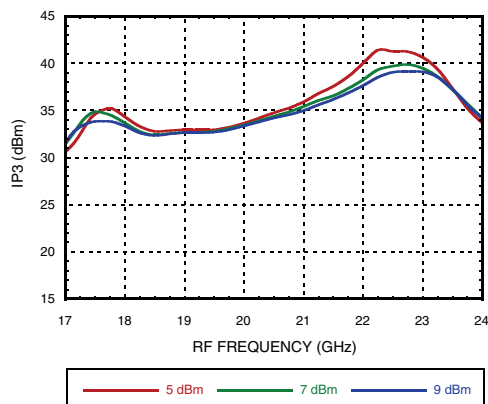
Side Band Rejection vs. Temperature

Input P1dB, USB vs. Temperature

Output P1dB, USB vs. Temperature

Input IP3, USB vs. Temperature

Output IP3, USB vs. Temperature

Input IP3, USB vs. LO Drive




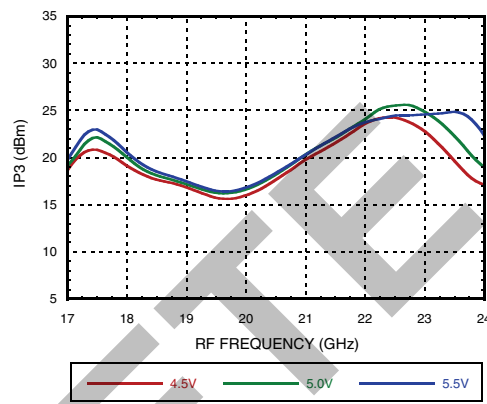
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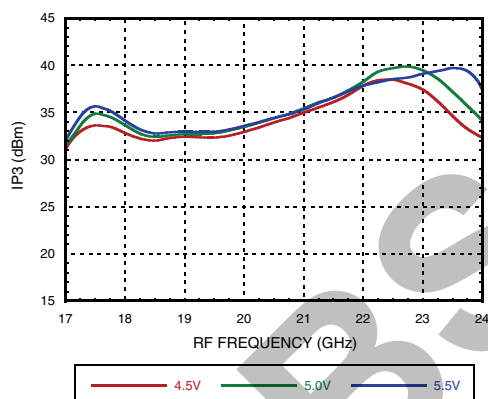
Output IP3, USB vs. LO Drive



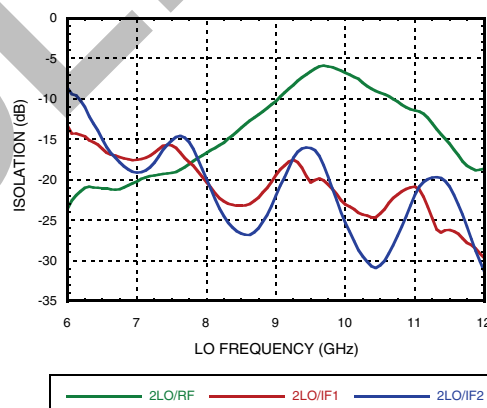
Input IP3, USB vs. Vdd



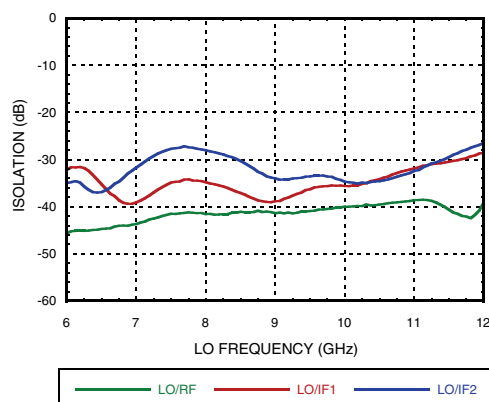
Output IP3, USB vs. Vdd



Isolations with 2LO ^[1]



Isolations with LO ^[1]



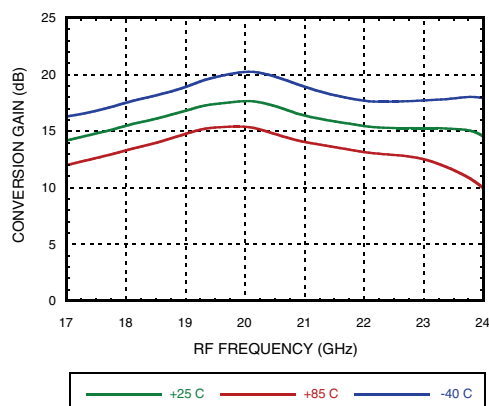
[1] Data taken without external IF 90° hybrid



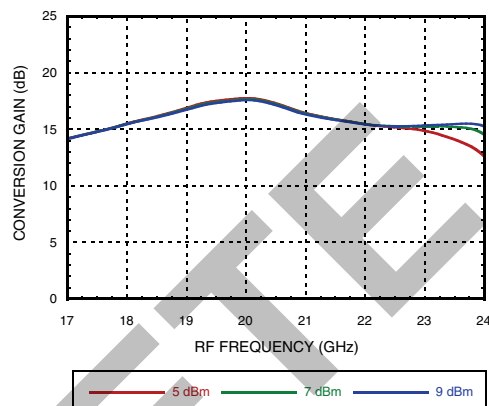
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Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 100 MHz

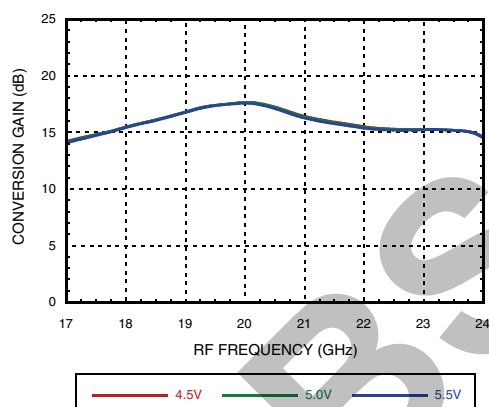
Conversion Gain, USB vs. Temperature



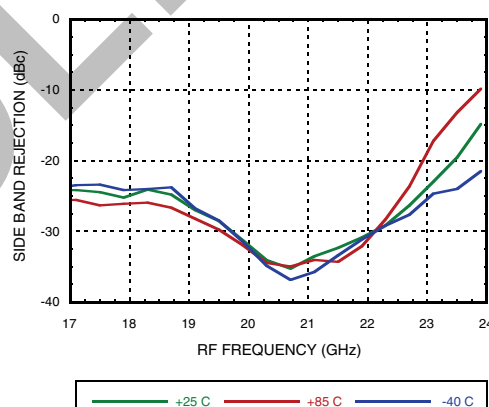
Conversion Gain, USB vs. LO Drive



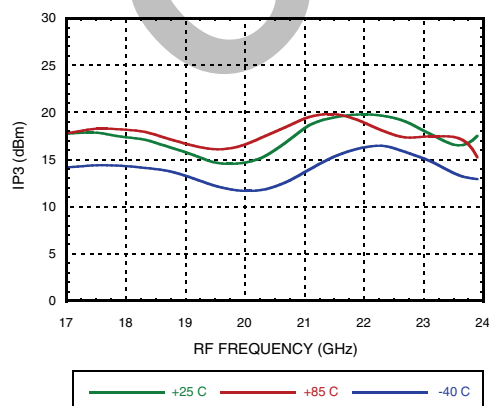
Conversion Gain, USB vs. Vdd



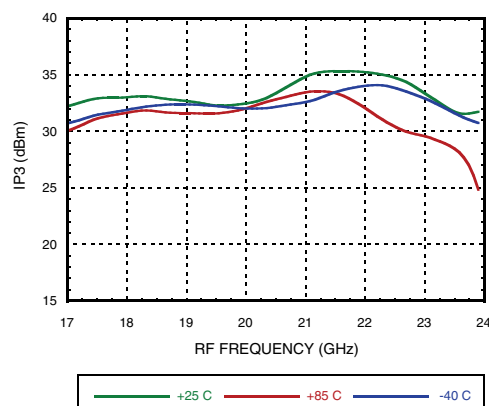
Sideband Rejection vs. Temperature



Input IP3, USB vs. Temperature

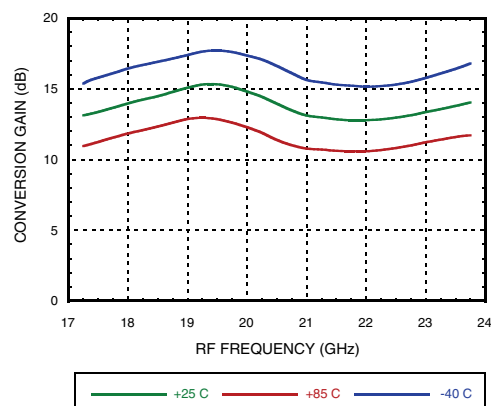
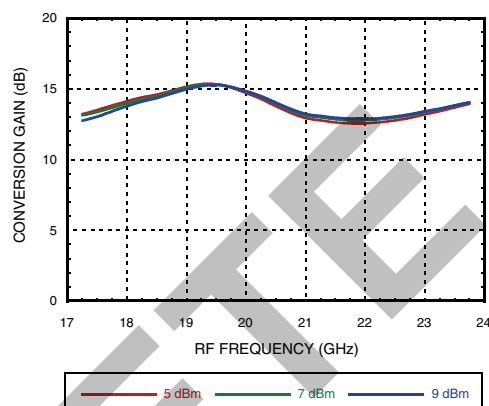
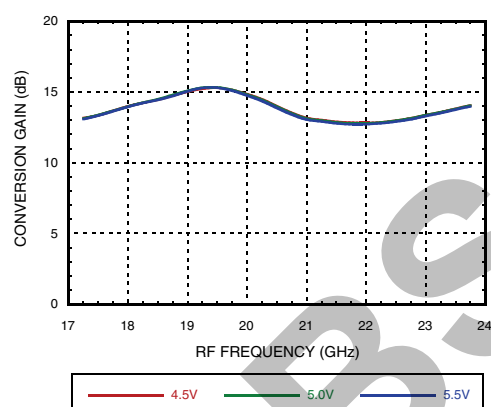
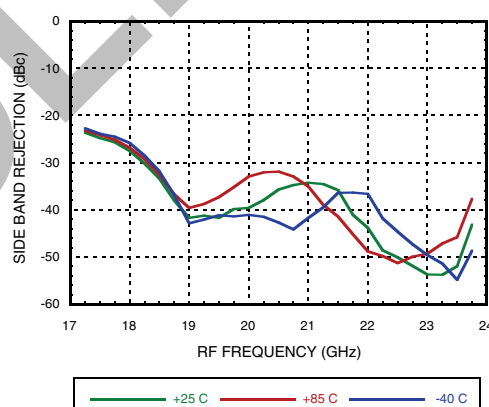
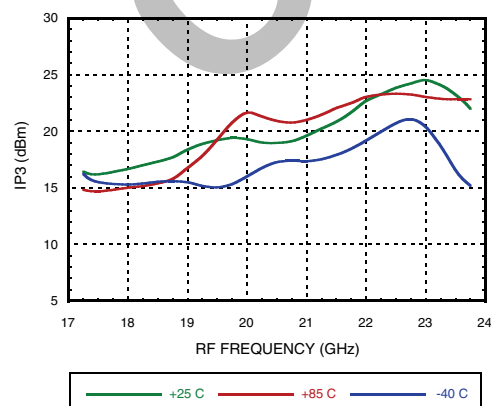
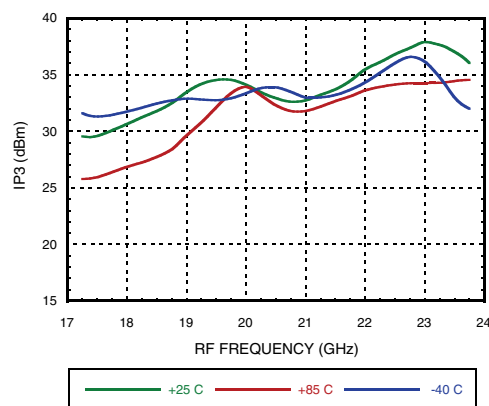


Output IP3, USB vs. Temperature



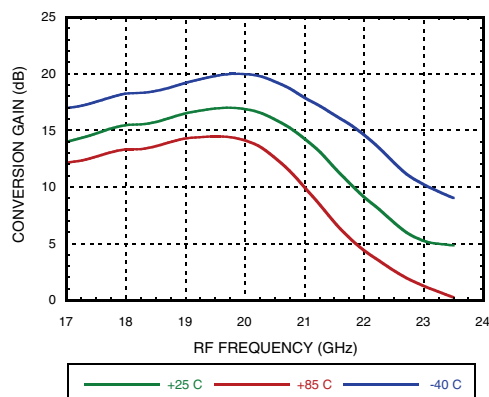
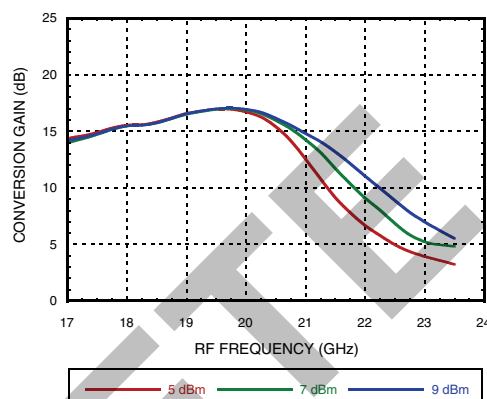
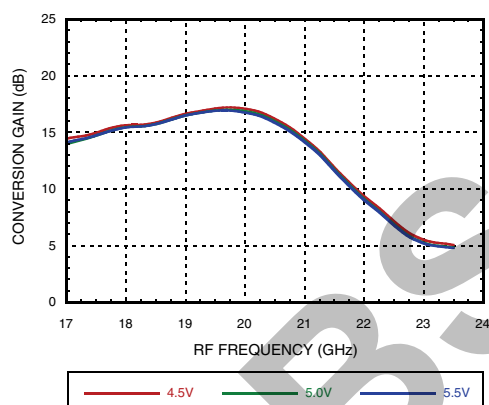
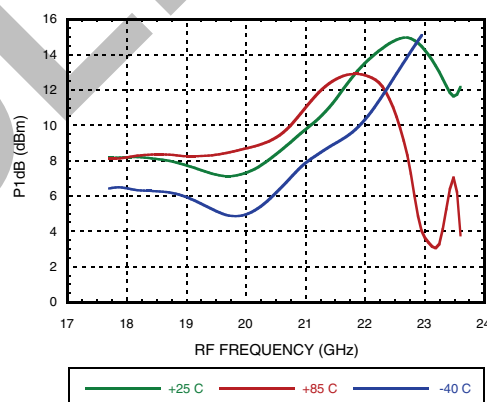
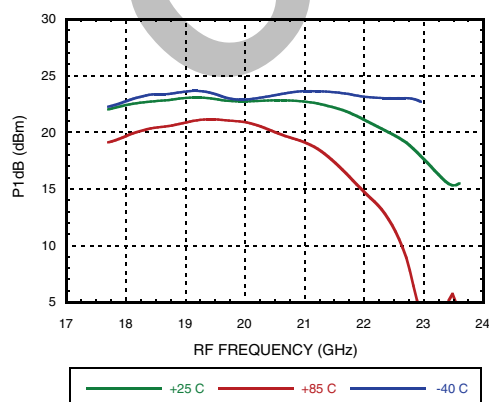
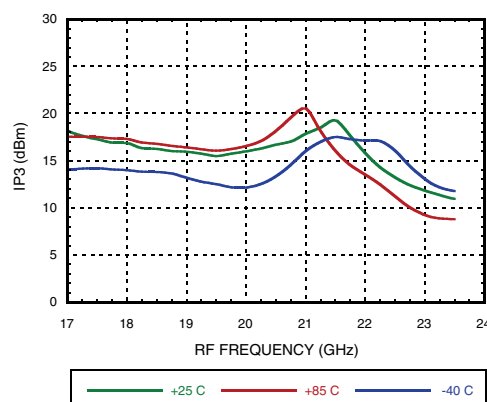

**GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz**

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 3750 MHz

Conversion Gain, USB vs. Temperature

Conversion Gain, USB vs. LO Drive

Conversion Gain, USB vs. Vdd

Sideband Rejection vs. Temperature

Input IP3, USB vs. Temperature

Output IP3, USB vs. Temperature



**GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz**

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2500 MHz

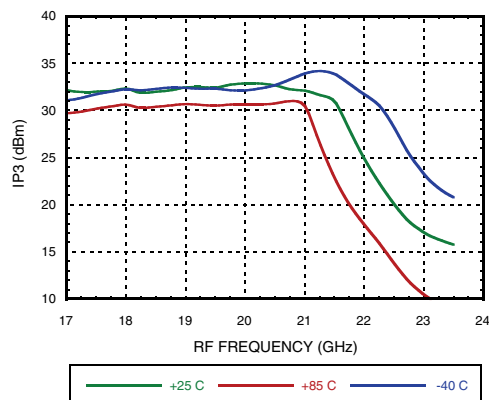
Conversion Gain, LSB vs. Temperature

Conversion Gain, LSB vs. LO Drive

Conversion Gain, LSB vs. Vdd

Input P1dB, LSB vs. Temperature

Output P1dB, LSB vs. Temperature

Input IP3, LSB vs. Temperature




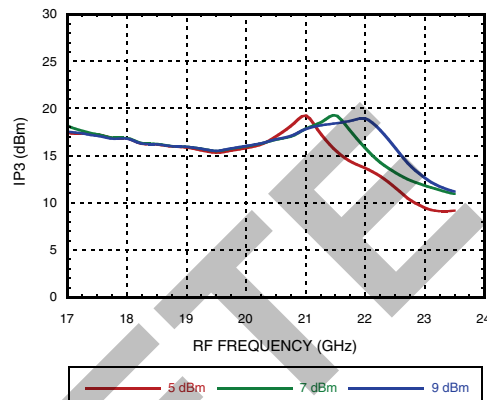
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17.6 - 23.7 GHz

Data Taken as SSB Upconverter with External IF 90° Hybrid, IF = 2500 MHz

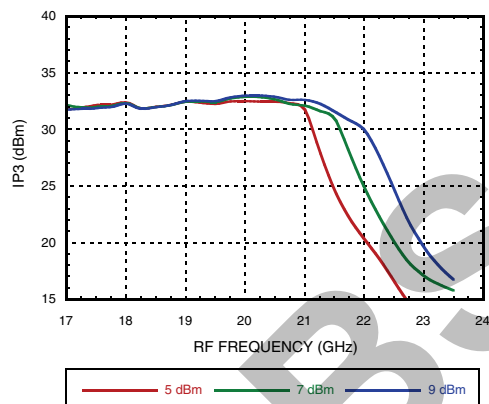
Output IP3, LSB vs. Temperature



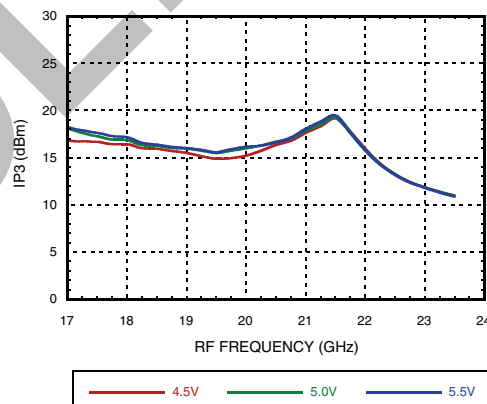
Input IP3, LSB vs. LO Drive



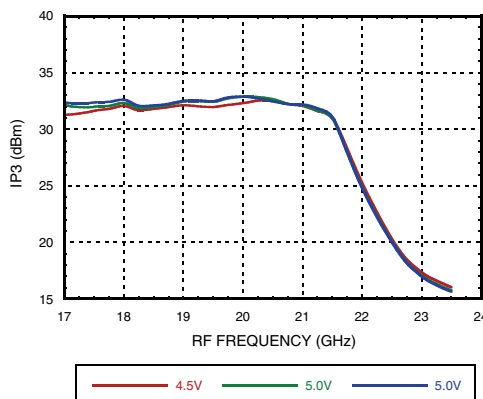
Output IP3, LSB vs. LO Drive



Input IP3, LSB vs. Vdd



Output IP3, LSB vs. Vdd

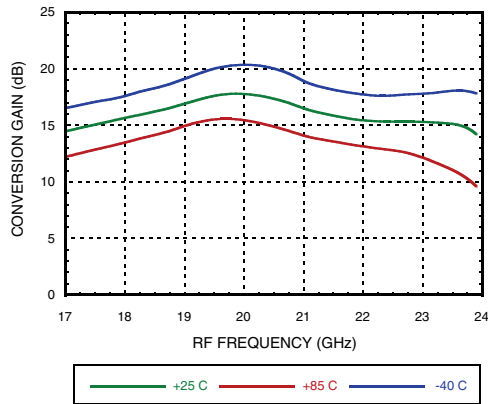




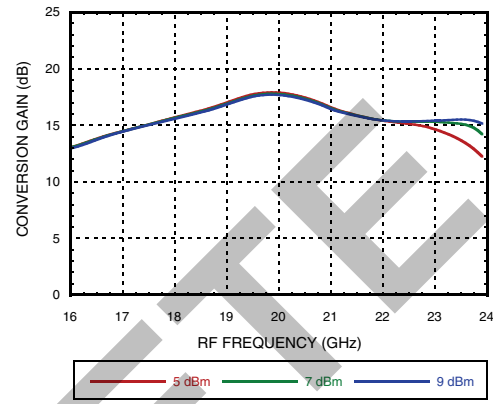
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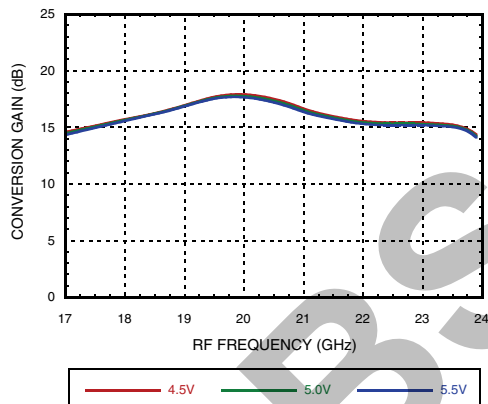
Conversion Gain, LSB vs. Temperature



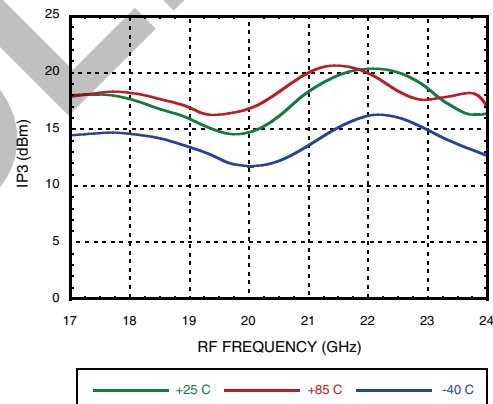
Conversion Gain, LSB vs. LO Drive



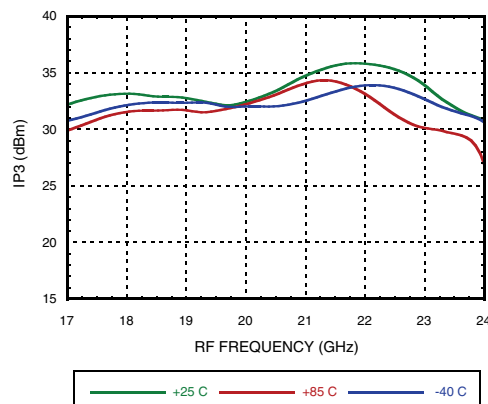
Conversion Gain, LSB vs. Vdd



Input IP3, LSB vs. Temperature



Output IP3, LSB vs. Temperature

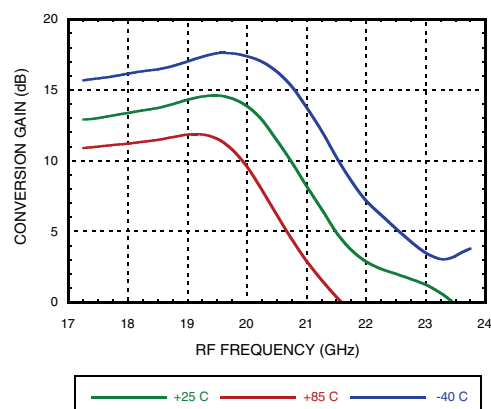




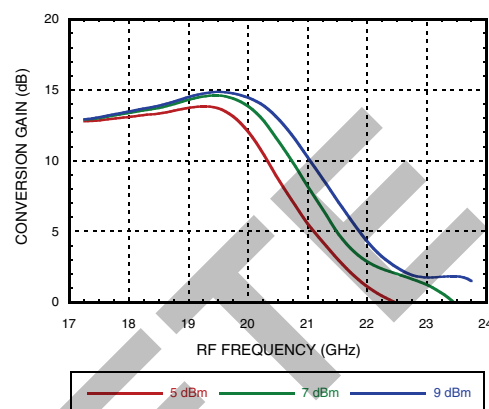
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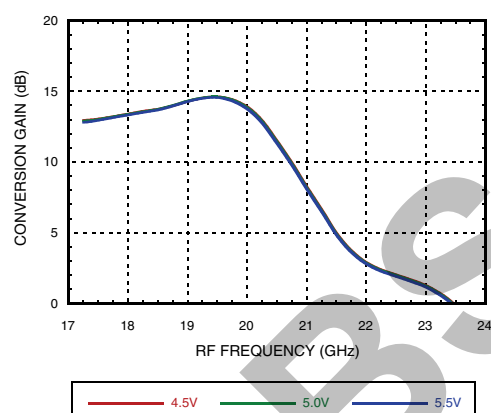
Conversion Gain, LSB vs. Temperature



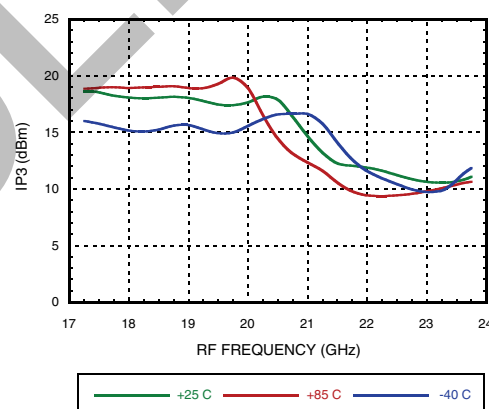
Conversion Gain, LSB vs. LO Drive



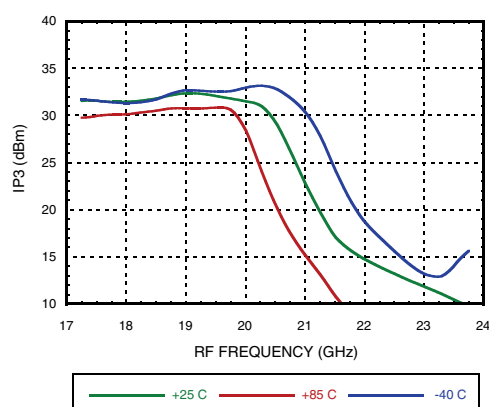
Conversion Gain, LSB vs. Vdd



Input IP3, LSB vs. Temperature



Output IP3, LSB vs. Temperature




**GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz**
MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-38.6	-11.6	-22.6	-46.6
1	-73.6	-78.6	0	-18.6	-53.6
2	-71.6	-73.6	-56.6	-77.6	-55.6
3	-115.6	-73.6	-68.6	-98.6	XX
4	-110.6	-94.6	-104.6	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 7.6 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-39.9	-11.9	-15.9	-51.9
1	-68.9	-67.9	0	-44.9	-55.9
2	-68.9	-66.9	-55.9	-82.9	-52.9
3	-112.9	-76.9	-71.9	-100.9	XX
4	-107.9	-98.9	-105.9	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 8.1 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-39.6	-8.4	-24.6	-42.6
1	-64.6	-63.6	0	-57.6	-54.6
2	-66.6	-71.6	-69.6	-94.6	-54.6
3	-103.6	-85.6	-66.6	-104.6	-103.6
4	-104.6	-102.6	-100.6	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 8.6 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-38.9	-3.9	-47.9	-49.9
1	-62.9	-55.9	0	-82.9	-51.9
2	-63.9	-58.9	-67.9	-88.9	-64.9
3	-100.9	-81.9	-65.9	-100.9	XX
4	-98.9	-106.9	-97.9	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 9.1 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-36.5	0.9	-49.5	-37.5
1	-62.5	-52.5	0	-76.5	-57.5
2	-58.5	-56.5	-54.5	-84.5	-64.5
3	-105.5	-87.5	-73.5	-102.5	XX
4	-99.5	-105.5	-99.5	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 9.6 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-33.7	-0.2	-48.7	-30.7
1	-62.7	-46.7	0	-73.7	-63.7
2	-56.7	-56.7	-69.7	-88.7	XX
3	-94.7	-86.7	-68.7	XX	XX
4	-91.7	XX	-97.7	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 10.1 GHz @ 7 dBm

[1] Data taken without external IF 90° hybrid

[2] All values in dBc below RF power level (2LO + IF) USB


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MxN Spurious Outputs ^{[1][2]}

	nLO				
mIF	0	1	2	3	4
0	X	-33.8	-1.5	-54.8	-30.8
1	-68.8	-45.8	0	-75.8	XX
2	-55.8	-51.8	-72.8	-83.8	XX
3	XX	-83.8	-66.8	XX	XX
4	-88.8	XX	XX	XX	XX

IF = 2.5 GHz @ -10 dBm

LO = 10.6 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][3]}

	nLO				
mIF	0	1	2	3	4
0	X	-37.9	-0.2	-49.2	-30.9
-1	-63.1	-100.6	0	-57.6	-46.3
-2	-62.7	-104.6	-57.8	-54.2	-51.9
-3	-101.6	-118.6	-73.1	-85.4	-92.6
-4	-97.6	XX	-108.6	XX	-98.6

IF = 2.5 GHz @ -10 dBm

LO = 10.1 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][3]}

	nLO				
mIF	0	1	2	3	4
0	X	-39	-4.3	-57	-34
-1	-71	-92	0	-66	-55
-2	-65	-105	-61	-79	-52
-3	-115	-120	-73	-88	-95
-4	-97	XX	-118	-110	-94

IF = 2.5 GHz @ -10 dBm

LO = 10.6 GHz @ 7 dBm

MxN Spurious Outputs ^{[1][3]}

	nLO				
mIF	0	1	2	3	4
0	X	-38.9	-5.9	-55.9	XX
-1	-66.9	-86.9	0	-78.9	-60.9
-2	-64.9	-94.9	-45.9	-94.9	-53.9
-3	-101.9	-120.9	-62.9	-88.9	-96.9
-4	-95.9	XX	-96.9	-117.9	-93.9

IF = 2.5 GHz @ -10 dBm

LO = 11.1 GHz @ 7 dBm

[1] Data taken without external IF hybrid

[2] All values in dBc below RF power level (2LO + IF) USB

[3] All values in dBc below RF power level (2LO - IF) LSB


**GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz**
Absolute Maximum Ratings

Drain Bias Voltage (Vdd1, 2, 3)	5.5V
Gate Bias Voltage (Vgg1, Vgg2)	-2.5V to 0V
IF Input Power (IF1, IF2)	20 dBm
LO Drive (LO IN)	+10 dBm
Channel Temperature	175 °C
Continuous Pdiss (T = 85°C) (derate 24.9 mW/°C above 85°C)	2.24 W
Thermal Resistance (channel to ground paddle)	40.2 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class 1A

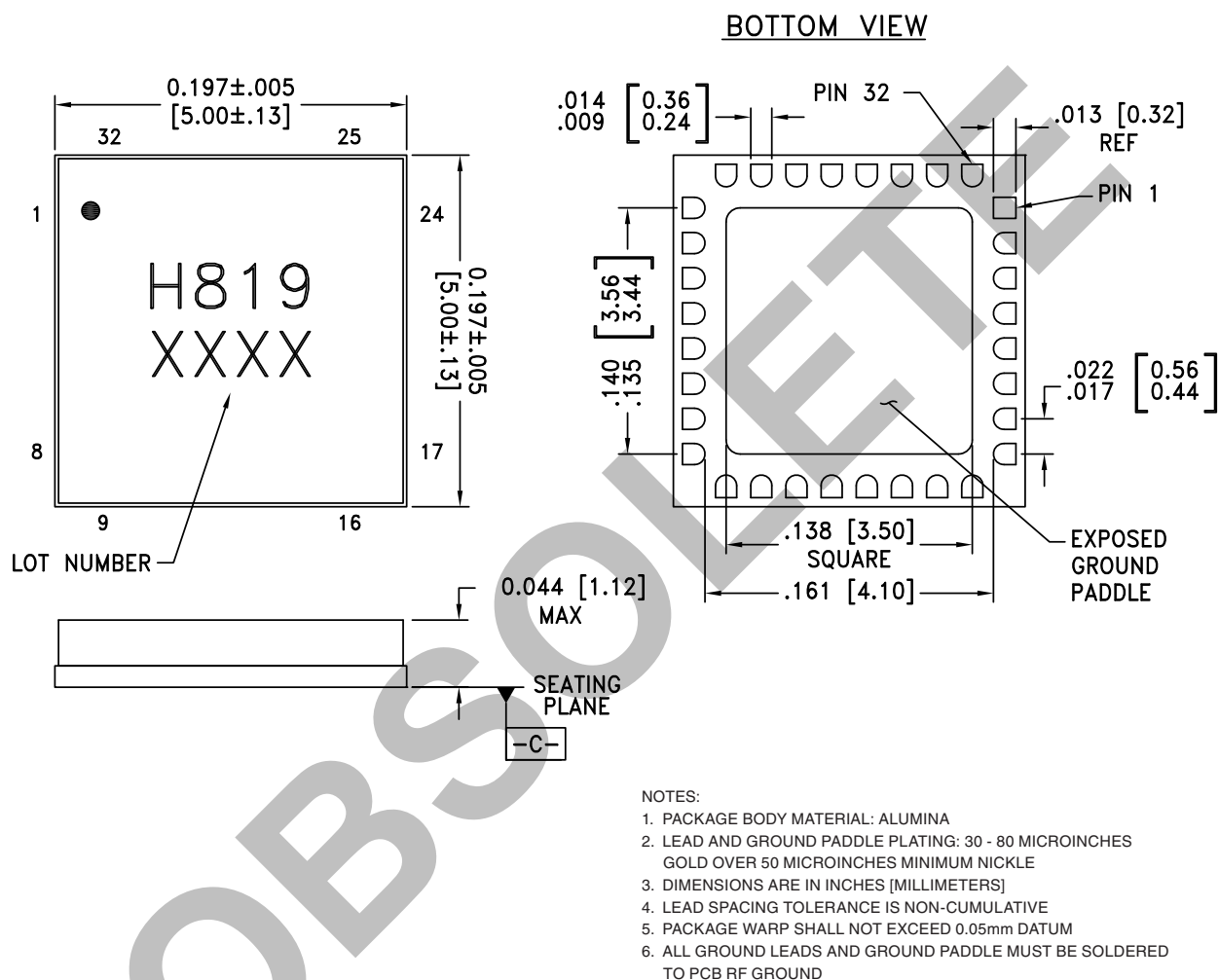
Harmonics of LO @ RF Output

LO Freq. (GHz)	nLO Spur @ RF Port			
	1	2	3	4
7.6	34	14	37	47
8.1	36	20	44	50
8.6	46	21	53	48
9.1	39	15	44	47
9.6	39	19	52	42
10.1	38	21	64	XX
10.6	37	20	56	XX
11.1	33	15	XX	XX

LO Power = +7 dBm

All values in dBc below input LO level, measured at RF port.


**ELECTROSTATIC SENSITIVE DEVICE
OBSERVE HANDLING PRECAUTIONS**

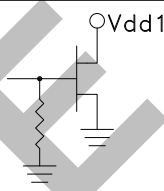
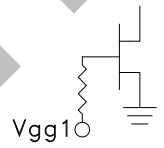
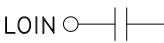
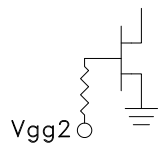
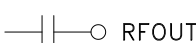
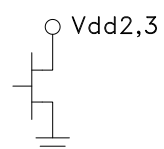
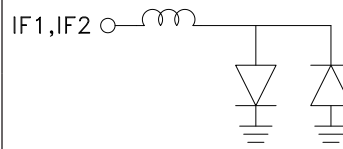

GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz
Outline Drawing

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[2]
HMC819LC5	Alumina, White	Gold over Nickel	MSL3 ^[1]	H819 XXXX

[1] Max peak reflow temperature of 260 °C

[2] 4-Digit lot number XXXX

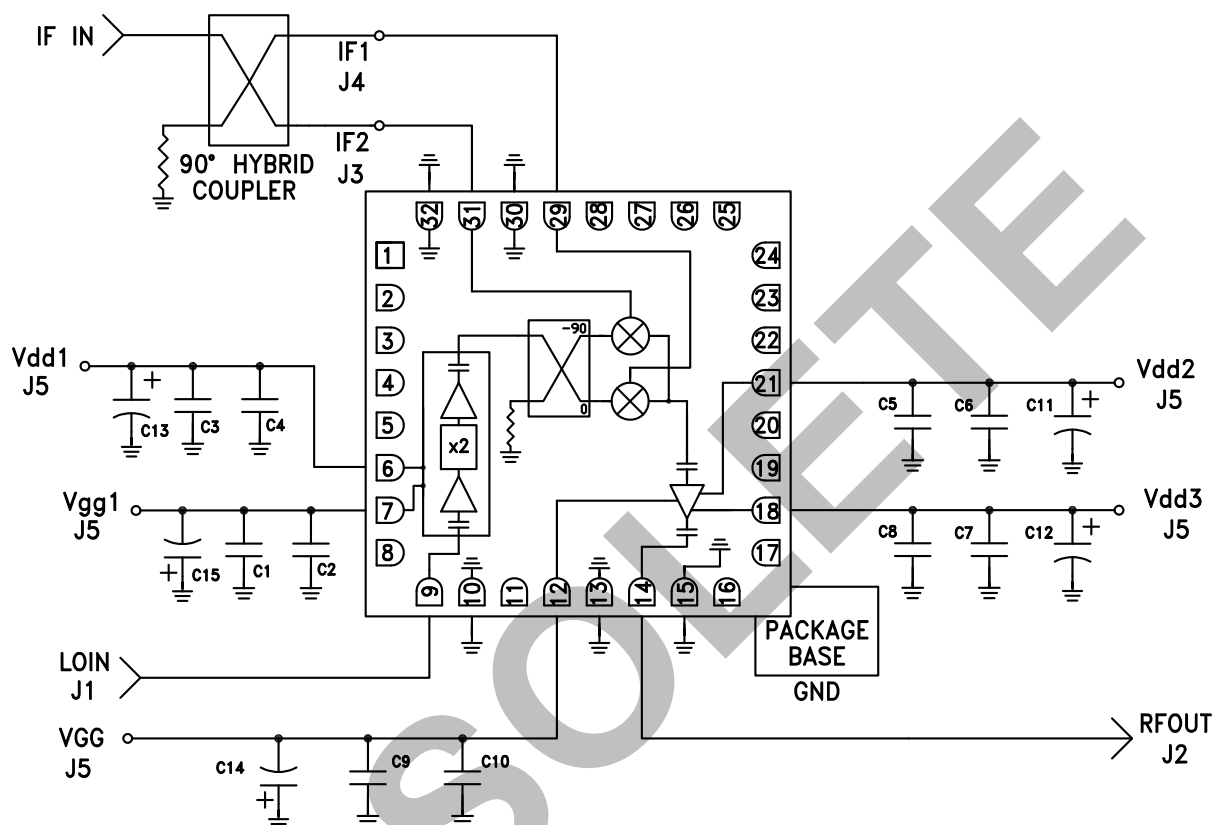

GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz
Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1 - 5, 8, 11, 16, 17, 19, 20, 22 - 28	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
6	Vdd1	Power supply voltage for x2 multiplier. See application circuit for required external components.	
7	Vgg1	Gate control for x2 multiplier, set to -1.7V. See application circuit for required external components.	
9	LOIN	This pin is AC coupled and matched to 50 Ohms.	
10, 13, 15, 30, 32	GND	These pins and package bottom must be connected to RF/DC ground.	
12	Vgg2	Gate control for RF amplifier, please follow "MMIC Amplifier Biasing Procedure" application note. See application circuit for required external components.	
14	RFOUT	This pin is AC coupled and matched to 50 Ohms.	
18, 21	Vdd3, Vdd2	Power supply voltage for RF amplifier. See application circuit for required external components.	
29	IF1	Differential IF input pins. For applications not requiring operation to DC, an off chip DC blocking capacitor should be used. For operation to DC this pin must not source/sink more than 3mA of current or part non function and possible part failure will result.	
31	IF2		

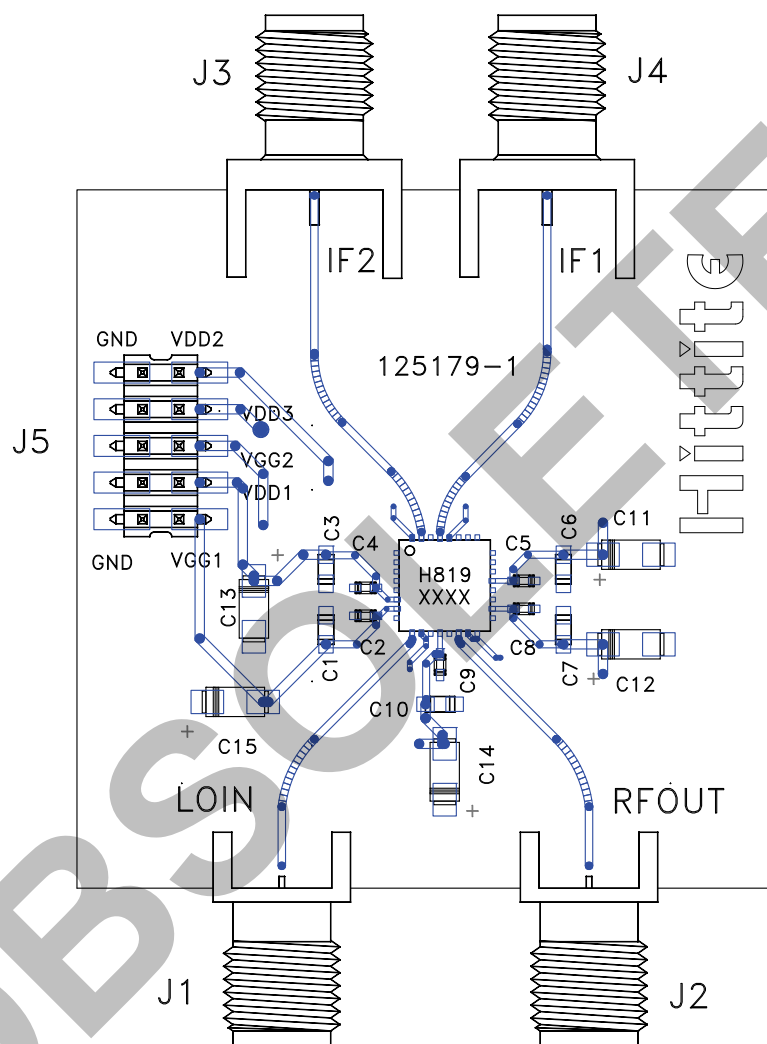


GaAs MMIC I/Q UPCONVERTER
17.6 - 23.7 GHz

Typical Application



C1, C3, C6, C7, C10	1000 pF
C2, C4, C5, C8, C9	100 pF
C11 - C15	2.2 μ F

Evaluation PCB

List of Materials for Evaluation PCB 127607 [1]

Item	Description
J1, J2	PCB Mount 2.92 mm Connector
J3, J4	PCB Mount SMA Connector
J5	2mm 10 Pos Vert SMT
C1, C3, C6, C7, C10	1000 pF Capacitor, 0603 Pkg.
C2, C4, C5, C8, C9	100 pF Capacitor, 0402 Pkg.
C11 - C15	2.2 μ F Tantalum Capacitor, Case A
U1	HMC819LC5 Upconverter
PCB [2]	125179 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

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